

## Features

- Glass Passivated Die Construction
- Super-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 100A Peak
- Low Forward Voltage Drop and High Current Capability
- Low Reverse Leakage Current
- Ideally Suited for Automated Assembly
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen- and Antimony-Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

## Mechanical Data

- Case: SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead-Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 **(Q3)**
- Polarity: Cathode Band
- Weight: 0.093 grams (Approximate)



Top View



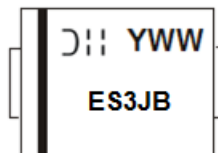
Bottom View

## Ordering Information (Note 4)

| Part Number | Qualification | Case | Packaging        |
|-------------|---------------|------|------------------|
| ES3JB-13-F  | Commercial    | SMB  | 3000/Tape & Reel |

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



ES3JB = Product Type Marking Code  
 DII = Manufacturers' Code Marking  
 YWW = Date Code Marking  
 Y = Last Digit of Year (ex: 0 for 2020)  
 WW = Week Code (01 to 53)

## Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

| Characteristic  | Symbol                          | Value | Unit |
|---|---------------------------------|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage (Note 5)     | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 600   | V    |
| RMS Reverse Voltage   | $V_{R(RMS)}$                    | 420   | V    |
| Average Rectified Output Current @ $T_T = +110^\circ\text{C}$                                       | $I_O$                           | 3.0   | A    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed on Rated Load | $I_{FSM}$                       | 100   | A    |

## Thermal Characteristics

| Characteristic  | Symbol          | Value       | Unit               |
|---|-----------------|-------------|--------------------|
| Typical Thermal Resistance, Junction to Ambient (Note 6)  | $R_{\theta JA}$ | 50          | $^\circ\text{C/W}$ |
| Typical Thermal Resistance, Junction to Terminal (Note 6) | $R_{\theta JT}$ | 15          | $^\circ\text{C/W}$ |
| Typical Thermal Resistance, Junction to Case (Note 6)     | $R_{\theta JC}$ | 15          | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range                   | $T_J, T_{STG}$  | -55 to +150 | $^\circ\text{C}$   |

## Electrical Characteristics (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic  | Symbol   | Value     | Unit          |
|---|----------|-----------|---------------|
| Max Forward Voltage<br>@ $I_F = 3.0\text{A}$                  | $V_{FM}$ | 1.30      | V             |
| Peak Reverse Current<br>at Rated DC Blocking Voltage (Note 5) | $I_{RM}$ | 10<br>500 | $\mu\text{A}$ |
| Typical Total Capacitance (Note 7)                            | $C_T$    | 45        | pF            |
| Maximum Reverse Recovery Time (Note 8)                        | $t_{rr}$ | 35        | ns            |
| Typical Reverse Recovery Time                                 | $t_{rr}$ | 30        | ns            |

- Notes:
5. Short duration pulse test used to minimize self-heating effect.
  6. Unit mounted on PC board with  $5.0\text{mm}^2$  (0.013mm thick) copper pads as heat sink.
  7. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
  8. Measured with  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $I_{rr} = 0.25\text{A}$ . See Figure 5.

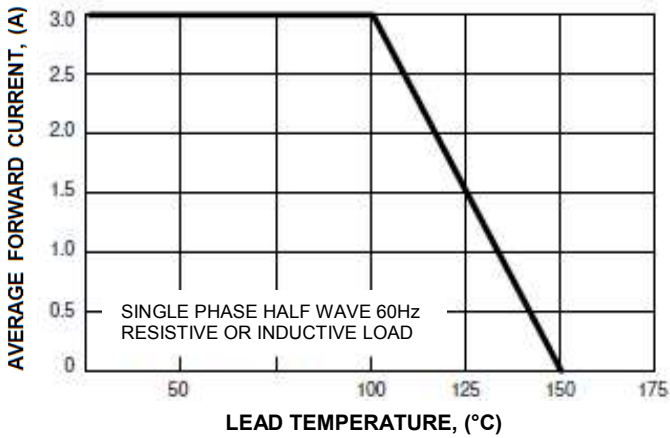


Fig. 1 Forward Current Derating Curve

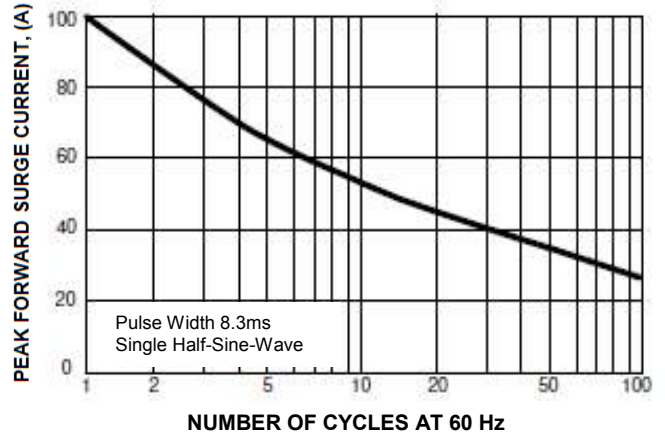


Fig. 2 Maximum Non-Repetitive Surge Current

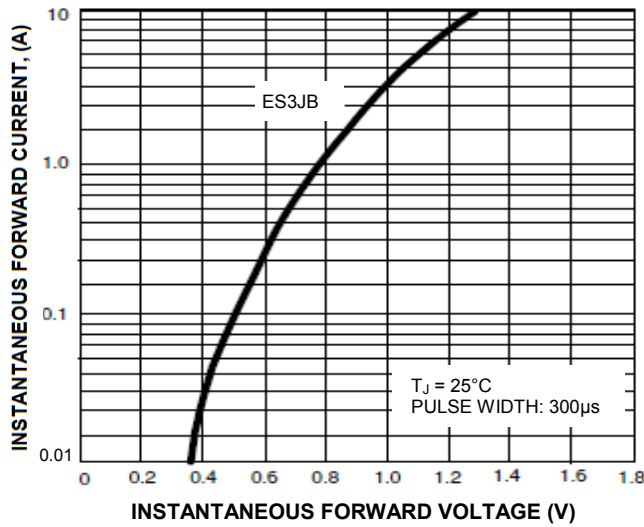


Fig. 3 Typical Forward Characteristics

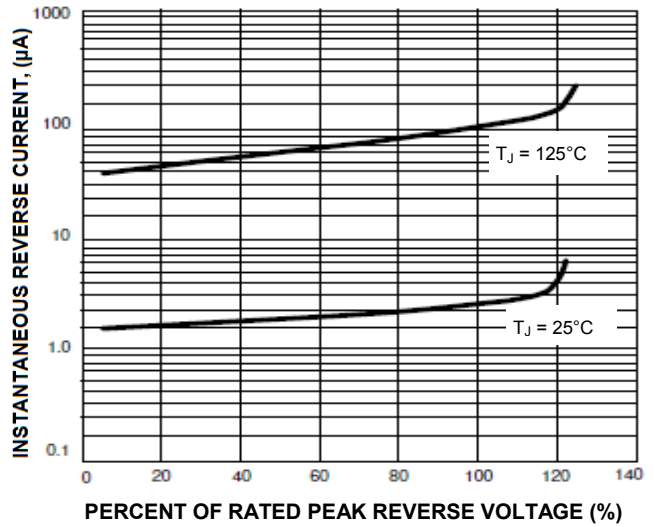
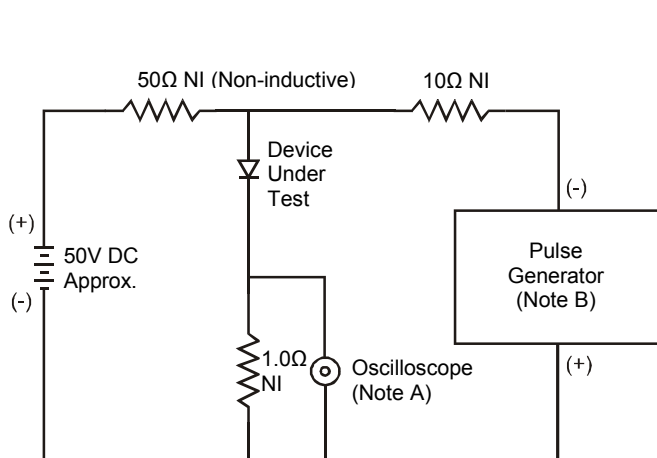


Fig. 4 Typical Reverse Characteristics



Notes:  
A. Rise Time = 7.0ns max. Input Impedance = 1.0 MΩ, 22pF.  
B. Rise Time = 10ns max. Input Impedance = 50Ω.

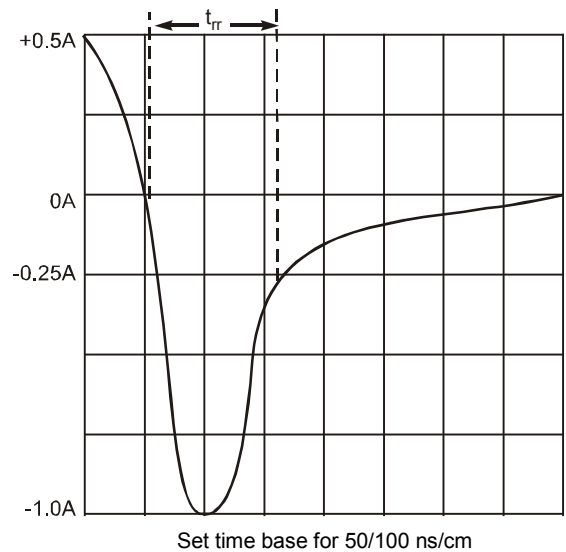
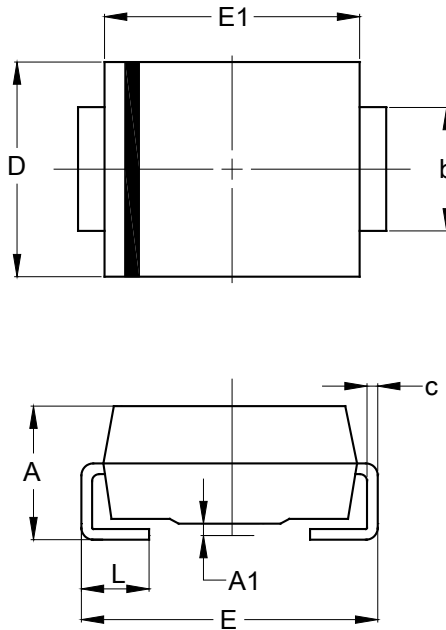


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SMB

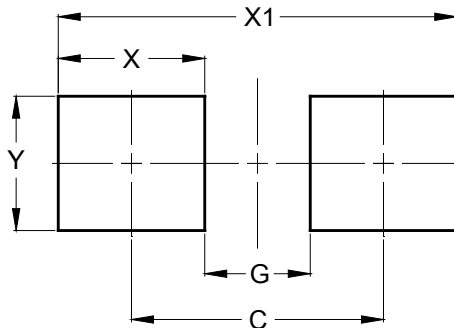


| SMB                  |      |      |
|----------------------|------|------|
| Dim                  | Min  | Max  |
| A                    | 2.00 | 2.50 |
| A1                   | 0.05 | 0.20 |
| b                    | 1.96 | 2.21 |
| c                    | 0.15 | 0.31 |
| D                    | 3.30 | 3.94 |
| E                    | 5.00 | 5.59 |
| E1                   | 4.06 | 4.57 |
| L                    | 0.76 | 1.52 |
| All Dimensions in mm |      |      |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SMB



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 4.30          |
| G          | 1.80          |
| X          | 2.50          |
| X1         | 6.80          |
| Y          | 2.30          |

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